Silicon N-Channel MOS FET

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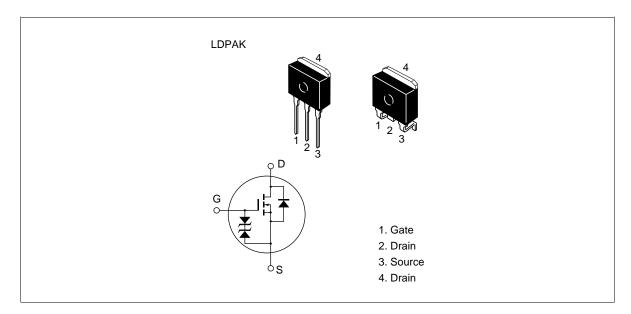
Application

High speed power switching

Features

- Low on-resistance
- High speed switching
- Low drive current
- No secondary breakdown
- Suitable for switching regulator, DC-DC converter and motor driver

Outline





Absolute Maximum Ratings (Ta = 25° C)

Item	Symbol	Ratings	Unit	
Drain to source voltage	V _{DSS}	150	V	
Gate to source voltage	V _{GSS}	±20	V	
Drain current	I _D	10	А	
Drain peak current	I _{D(pulse)} *1	40	А	
Body to drain diode reverse drain current	I _{DR}	10	А	
Channel dissipation	Pch*2	50	W	
Channel temperature	Tch	150	°C	
Storage temperature	Tstg	-55 to +150	°C	

Notes 1. PW 10 µs, duty cycle 1%

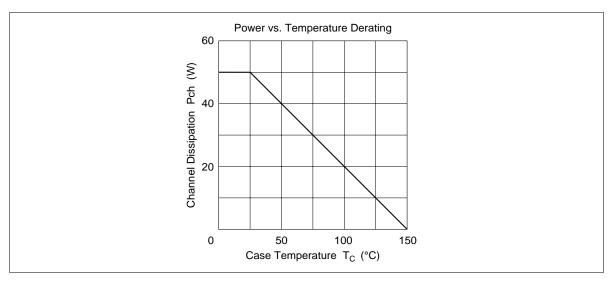
2. Value at $T_c = 25^{\circ}C$

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Electrical Characteristics (Ta = 25°C)

Item	Symbol	Min	Тур	Max	Unit	Test conditions
Drain to source breakdown voltage	$V_{(\text{BR})\text{DSS}}$	150	_	_	V	$I_{\rm D} = 10$ mA, $V_{\rm GS} = 0$
Gate to source breakdown voltage	$V_{(BR)GSS}$	±20	_	_	V	$I_{G} = \pm 100 \ \mu A, \ V_{DS} = 0$
Gate to source leak current	I _{GSS}	_	_	±10	μΑ	$V_{GS} = \pm 16 V, V_{DS} = 0$
Zero gate voltage drain current	I _{DSS}	—	_	250	μA	$V_{\rm DS} = 120 \ V, \ V_{\rm GS} = 0$
Gate to source cutoff voltage	$V_{\text{GS(off)}}$	2.0	_	4.0	V	$I_{\rm D} = 1 \text{ mA}, V_{\rm DS} = 10 \text{ V}$
Static Drain to source on state resistance	$R_{\text{DS(on)}}$	—	0.12	0.15		$I_{\rm D} = 5$ A, $V_{\rm GS} = 10$ V * ¹
Forward transfer admittance	yfs	4.0	7.0	_	S	$I_{\rm D} = 5 \text{ A}, V_{\rm DS} = 10 \text{ V}^{*1}$
Input capacitance	Ciss	_	1200	_	pF	$V_{DS} = 10 \text{ V}, \text{ V}_{GS} = 0,$
Output capacitance	Coss	—	550		pF	f = 1 MHz
Reverse transfer capacitance	Crss	—	85	_	pF	
Turn-on delay time	t _{d(on)}	_	20	_	ns	$I_{\rm D} = 5 \text{ A}, \text{ V}_{\rm GS} = 10 \text{ V},$
Rise time	t,	—	50		ns	$R_{L} = 6$
Turn-off delay time	t _{d(off)}	_	70	_	ns	
Fall time	t _f	_	40	_	ns	
Body to drain diode forward voltage	V_{DF}	_	1.2	_	V	$I_{\rm F} = 10$ A, $V_{\rm GS} = 0$
Body to drain diode reverse recovery time	t _{rr}	—	220	—	ns	$I_{_{\rm F}} = 10 \text{ A}, V_{_{\rm GS}} = 0,$ $di_{_{\rm F}}/dt = 50 \text{ A}/\mu \text{s}$
Note 1. Pulse test						

See characteristic curves of 2SK740.



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